

9. I-V relationships in active region: (Low to medium freq.)

$$i_E = i_C + i_B = (1 + \beta) i_B$$

$$i_C = \beta \cdot i_B = \alpha \cdot i_E = \left(\frac{\beta}{1 + \beta} \right) i_E$$

$$\alpha = \frac{\beta}{1 + \beta}$$

$$\beta = \frac{\alpha}{1 - \alpha}$$

npn

$$i_C = I_S \cdot e^{\frac{V_{BE}}{V_T}}$$

$$i_E = \frac{i_C}{\alpha} = \frac{I_S \cdot e^{\frac{V_{BE}}{V_T}}}{\alpha}$$

$$i_B = \frac{i_C}{\beta} = \frac{I_S \cdot e^{\frac{V_{BE}}{V_T}}}{\beta}$$

pnp

$$i_C = I_S \cdot e^{\frac{V_{EB}}{V_T}}$$

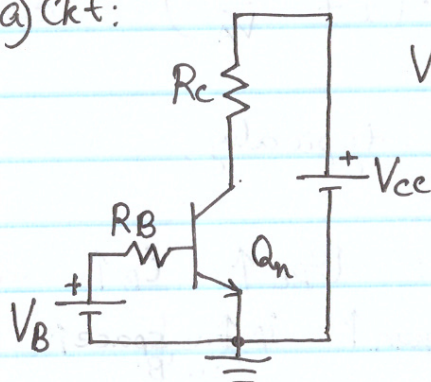
$$i_E = \frac{i_C}{\alpha} = \frac{I_S \cdot e^{\frac{V_{EB}}{V_T}}}{\alpha}$$

$$i_B = \frac{i_C}{\beta} = \frac{I_S \cdot e^{\frac{V_{EB}}{V_T}}}{\beta}$$

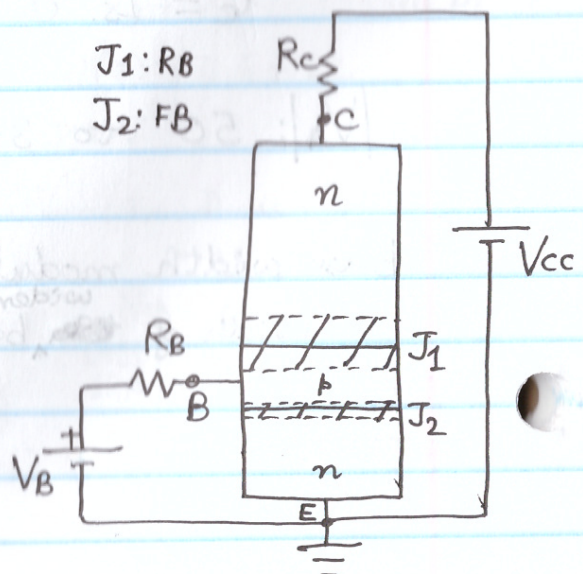
(without early effect).

10. Active region in common-emitter configuration: ^{CE}

a) Ckt:



(or)

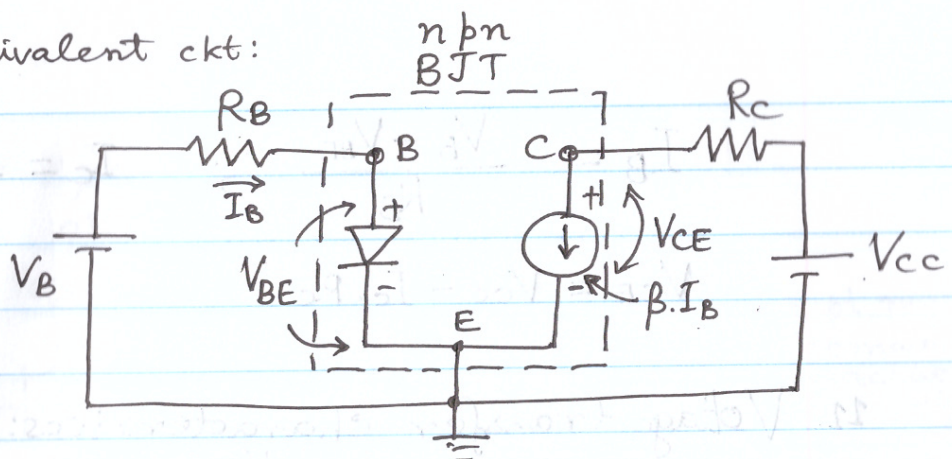


$J_1 \Rightarrow$ Reverse biased junction

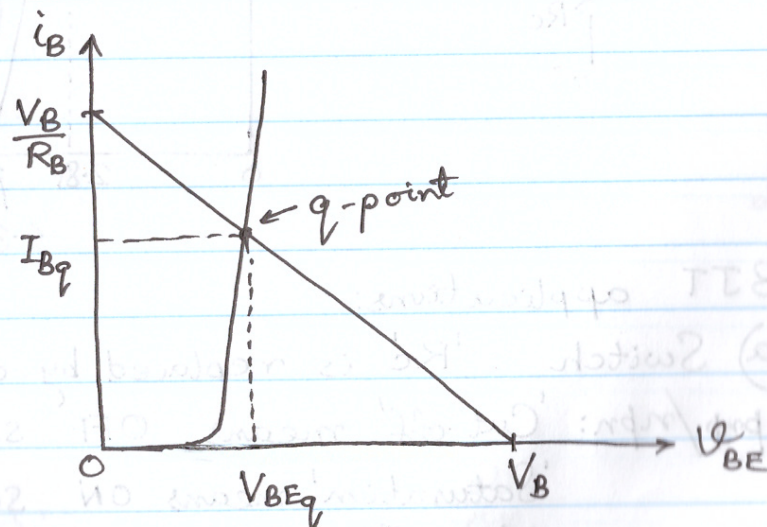
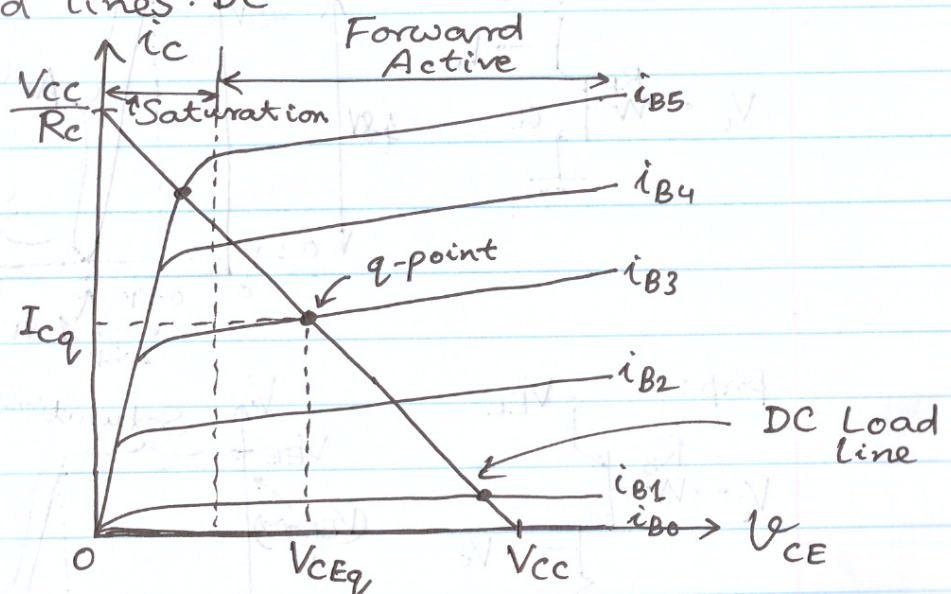
$J_2 \Rightarrow$ Forward biased junction

b. Equivalent ckt:

(or)



c. Load lines: DC



$$I_B = \frac{V_B - V_{BE}}{R_B} ; \quad I_C = \frac{V_{CC} - V_{CE}}{R_C}$$

$$V_{CE} = V_{CC} - I_C \cdot R_C$$

11. Voltage transfer characteristics: CE

npn:

